100V 175°C NPN LOW SAT MEDIUM POWER TRANSISTOR IN POWERDI5060-8

Features

- BV_{CEO} > 100V
- I_C = 3A Continuous Collector Current
- I_{CM} = 6A Peak Pulse Current
- $R_{CE(SAT)}$ <150mΩ
- Rated to +175°C—Ideal for High Ambient Temperature Environments
- Wettable Flank for Improved Optical Inspection
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The DXTN3C100PSQ is suitable for automotive applications requiring specific change control and is AEC-Q101 qualified, is PPAP capable, and is manufactured in IATF16949:2016 certified facilities.**

Mechanical Data

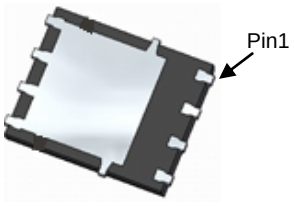
- Case: PowerDI®5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Finish—Matte Tin Annealed Over Copper Leadframe; Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.097 grams (Approximate)

Applications

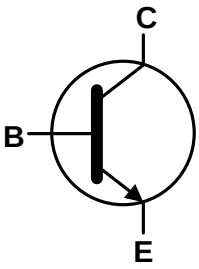
- Power Management
- Load Switch
- Linear Mode Voltage Regulator
- Backlighting Applications

PowerDI5060-8 (SWP) (Type Q)

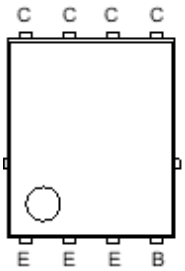
Top View



Bottom View



Internal Schematic



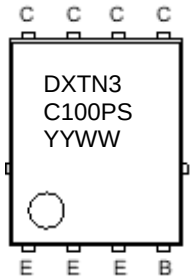
Top View
Pin Configuration

Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXTN3C100PSQ-13	Automotive	DXTN3C100PS	13	12	2500

Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



DXTN3 = Product Type Marking Code
C100PS = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 19 = 2019)
WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	100	V
Collector-Emitter Voltage	V_{CEO}	100	V
Emitter-Base Voltage	V_{EBO}	7	V
Base Current	I_B	500	mA
Continuous Collector Current	I_C	3	A
Peak Pulse Collector Current	I_{CM}	6	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

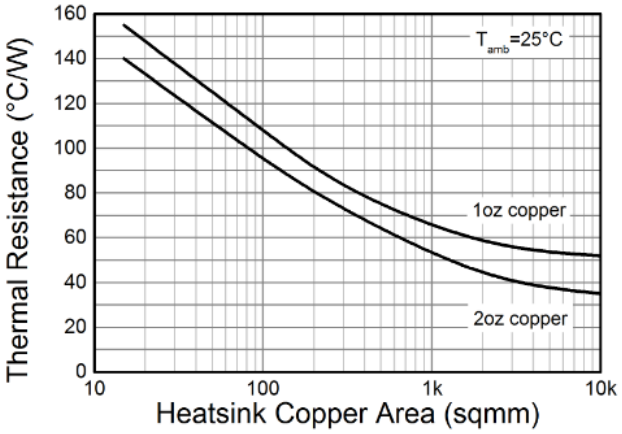
Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_D	2.5	W
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	60	°C/W
	(Note 6)		140	
Thermal Resistance, Junction to Lead	(Note 7)	$R_{\theta JL}$	5.7	°C/W
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +175	°C

ESD Ratings (Note 8)

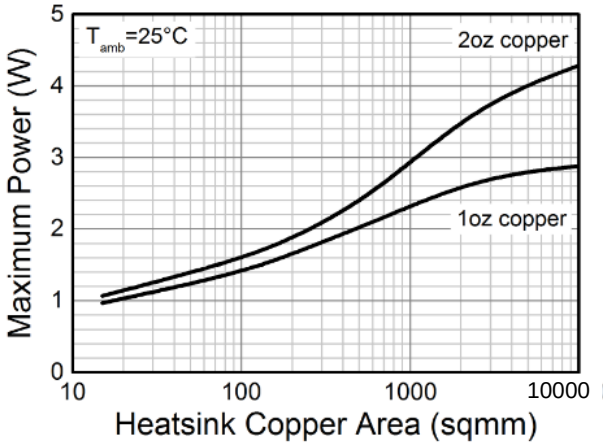
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:
5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Same as note (5), except mounted on minimum recommended pad layout.
7. Thermal resistance from junction to solder point (at the collector tab).
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

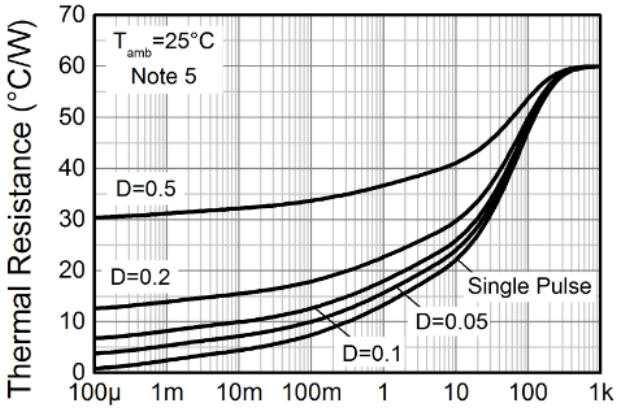
Typical Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)



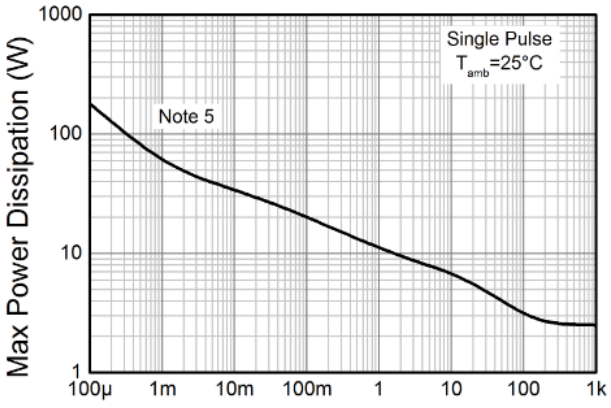
Thermal Resistance vs. Copper Area



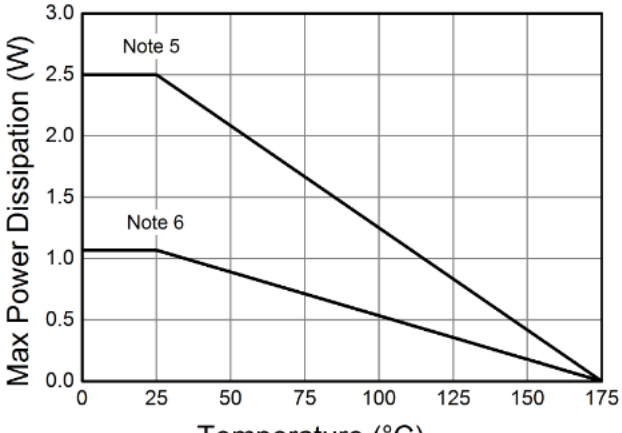
Max Power Dissipation vs. Copper Area



Transient Thermal Impedance



Pulse Power Dissipation



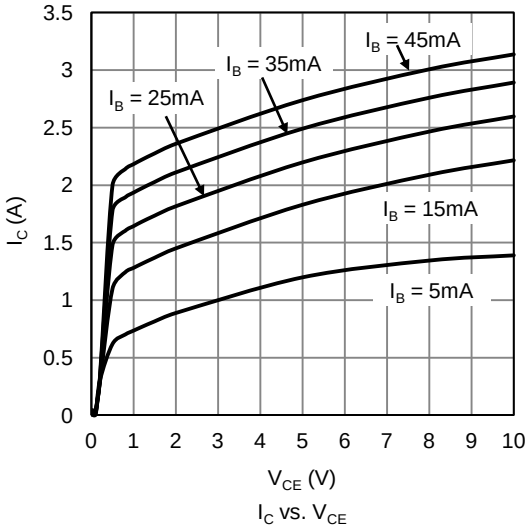
Derating Curve

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

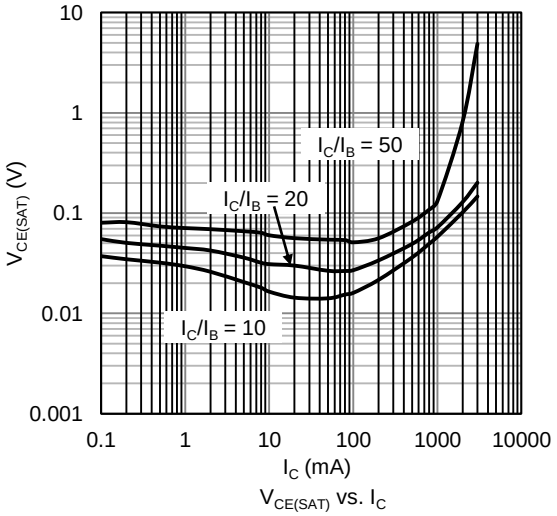
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV_{CBO}	100	—	—	V	I_C = 100µA
Collector-Emitter Breakdown Voltage (Note 9)	BV_{CEO}	100	—	—	V	I_C = 10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	7	—	—	V	I_E = 100µA
Collector-Base Cutoff Current	I_{CBO}	—	—	100	nA	V_{CB} = 80V
		—	—	50	µA	V_{CB} = 80V @ T_J = +150°C
Emitter Cutoff Current	I_{EBO}	—	—	100	nA	V_{EB} = 7V
Collector-Emitter Cutoff Current	I_{CES}	—	—	100	nA	V_{CES} = 80V
ON CHARACTERISTICS (Note 9)						
DC Current Gain	h_{FE}	150	250	—	—	I_C = 500mA, V_{CE} = 10V
		80	250	—		I_C = 1A, V_{CE} = 10V
		20	100	—		I_C = 2A, V_{CE} = 10V
		10	40	—		I_C = 3A, V_{CE} = 10V
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	90	150	mV	I_C = 1A, I_B = 50mA
		—	225	330	mV	I_C = 3A, I_B = 300mA
Collector-Emitter Saturation Resistance	$R_{CE(SAT)}$	—	90	150	mΩ	I_C = 1A, I_B = 50mA
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	—	0.86	1.0	V	I_C = 1A, I_B = 50mA
		—	1.0	1.2		I_C = 2A, I_B = 200mA
Base-Emitter Turn-On Voltage	$V_{BE(ON)}$	—	0.67	0.85	V	I_C = 0.1A, V_{CE} = 2V
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f_T	—	140	—	MHz	V_{CE} = 10V, I_C = 100mA, f = 100MHz
Output Capacitance	C_{obo}	—	11	—	pF	V_{CB} = 10V, f = 1MHz
Delay Time	t_d	—	20	—	ns	V_{CC} = 12.5V, I_C = 1A I_{B1} = -I_{B2} = 0.05A
Rise Time	t_r	—	300	—	ns	
Turn-On Time	$t_{(on)}$	—	320	—	ns	
Storage Time	t_s	—	830	—	ns	
Fall Time	t_f	—	470	—	ns	
Turn-Off Time	$t_{(off)}$	—	1300	—	ns	

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

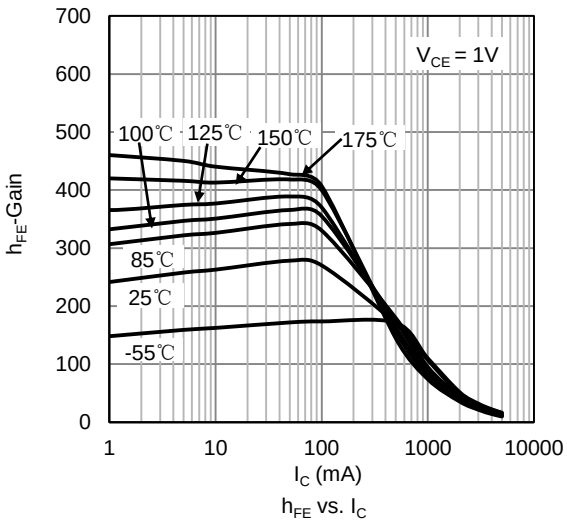
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



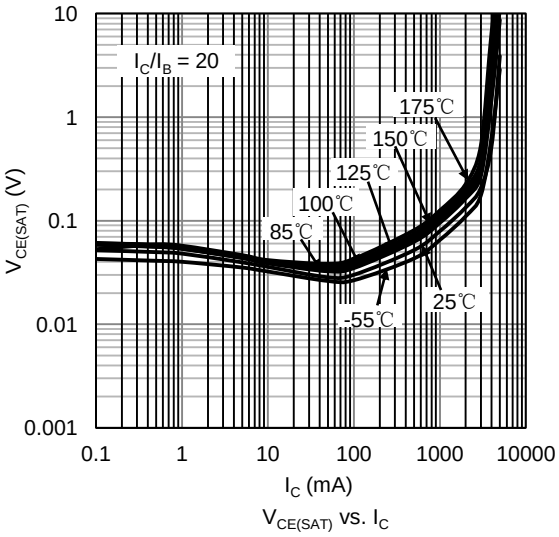
I_C vs. V_{CE}



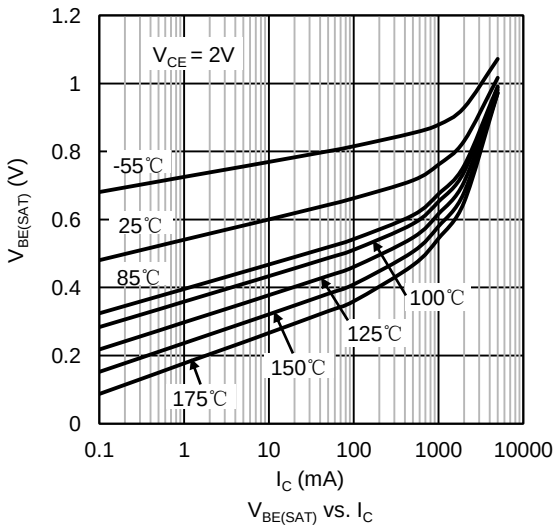
$V_{CE(SAT)}$ vs. I_C



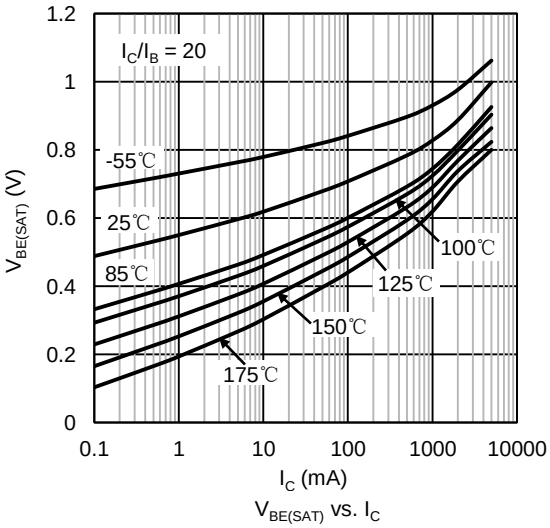
h_{FE} vs. I_C



$V_{CE(SAT)}$ vs. I_C



$V_{BE(SAT)}$ vs. I_C

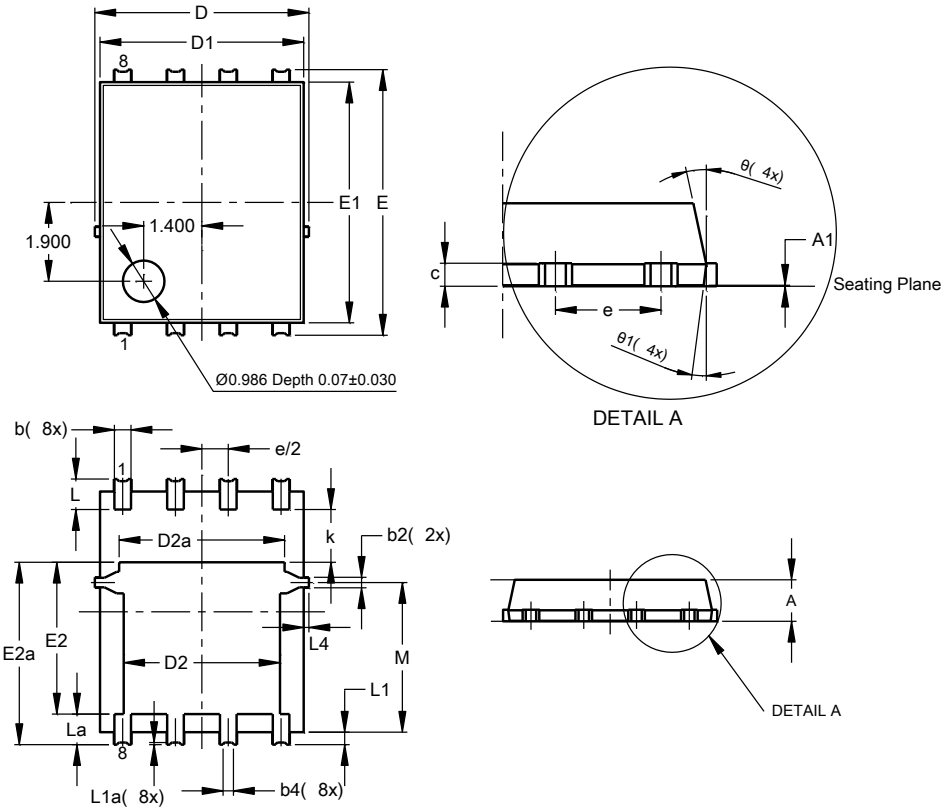


$V_{BE(SAT)}$ vs. I_C

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (SWP) (Type Q)

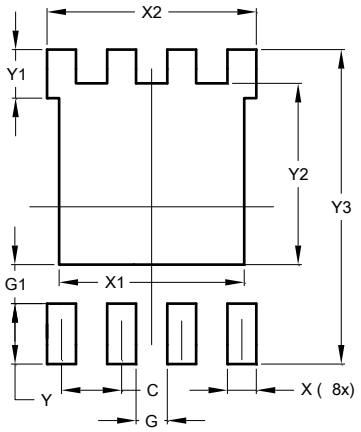


PowerDI5060-8 (SWP) (Type Q)			
Dim	**Min**	**Max**	**Typ**
A	0.90	1.10	1.00
A1	0	0.05	—
b	0.30	0.50	0.41
b2	0.20	0.35	0.25
b4	0.25REF		
c	0.230	0.330	0.277
D	5.15 BSC		
D1	4.70	5.10	4.90
D2	3.56	3.96	3.76
D2a	3.78	4.18	3.98
E	6.40 BSC		
E1	5.60	6.00	5.80
E2	3.46	3.86	3.66
E2a	4.195	4.595	4.395
e	1.27BSC		
k	1.05	—	—
L	0.635	0.835	0.735
La	0.635	0.835	0.735
L1	0.200	0.400	0.300
L1a	0.050REF		
L4	0.025	0.225	0.125
M	3.205	4.005	3.605
θ	10°	12°	11°
θ1	6°	8°	7°
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (SWP) (Type Q)



Dimensions	Value (in mm)
C	1.270
G	0.660
G1	0.820
X	0.610
X1	4.100
X2	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610

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